

MCT5200 MCT5201 MCT5210 MCT5211

Description

The MCT52XX series consists of a high-efficiency AlGaAs, infrared emitting diode, coupled with an NPN phototransistor in a six pin dual-in-line package.

The MCT52XX is well suited for CMOS to LSTT/TTL interfaces, offering 250% CTR_{CE(SAT)} with 1 mA of LED input current. When an LED input current of 1.6 mA is supplied data rates to 20K bits/s are possible.

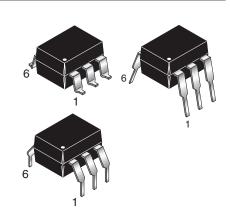
The MCT52XX can easily interface LSTTL to LSTTL/TTL, and with use of an external base to emitter resistor data rates of 100K bits/s can be achieved.

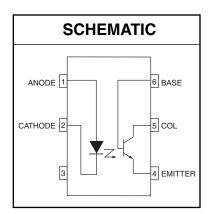
Features

- High CTR_{CE(SAT)} comparable to Darlingtons
- CTR guaranteed 0°C to 70°C
- High common mode transient rejection 5kV/µs
- Data rates up to 150 kbits/s (NRZ)
- Underwriters Laboratory (UL) recognized (file #E90700)
- VDE recognized (file #94766)
 - Add option 300 (e.g., MCT5211.300)

Applications

- CMOS to CMOS/LSTTL logic isolation
- LSTTL to CMOS/LSTTL logic isolation
- RS-232 line receiver
- Telephone ring detector
- AC line voltage sensing
- · Switching power supply





Parameters	Symbol	Device	Value	Units
TOTAL DEVICE				
Storage Temperature	T _{STG}	All	-55 to +150	°C
Operating Temperature	T _{OPR}	All	-55 to +100	°C
Lead Solder Temperature	T _{SOL}	All	260 for 10 sec	°C
Total Device Power Dissipation @ 25°C (LED plus detector)	В	All	260	mW
Derate Linearly From 25°C	P _D	All	3.5	mW/°C
EMITTER				
Continuous Forward Current	I _F	All	50	mA
Reverse Input Voltage	V _R	All	6	V
Forward Current - Peak (1 µs pulse, 300 pps)	I _F (pk)	All	3.0	А
LED Power Dissipation	В	All	75	mW
Derate Linearly From 25°C	P _D	All	1.0	mW/°C
DETECTOR				
Continuous Collector Current	Ic	All	150	mA
Detector Power Dissipation	В	All	150	mW
Derate Linearly from 25°C	P _D	All	2.0	mW/°C



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ELECTRICAL CHARACTERISTICS (T _A = 25°C Unless otherwise specified.)								
INDIVIDUA	L COMPONENT (CHARACTERISTICS						
Parameters		Test Conditions	Symbol	Device	Min	Тур**	Max	Units
EMITTER								
Input Forward \	Voltage Voltage	$(I_F = 5 \text{ mA})$	V _F	All		1.25	1.5	V
Forward Voltage Temp. Coefficient		(I _F = 2 mA)	$\frac{\Delta V_F}{\Delta T_A}$	All		-1.75		mV/ °C
Reverse Voltag	е	(I _R = 10 μA)	V _R	All	6			٧
Junction Capac	citance	(V _F = 0 V, f = 1.0 MHz)	CJ	All		18		pF
DETECTOR								
Collector-Emitter Breakdown Voltage		$(I_C = 1.0 \text{ mA}, I_F = 0)$	BV _{CEO}	All	30	100		V
Collector-Base Breakdown Voltage		$(I_C = 10 \mu A, I_F = 0)$	BV _{CBO}	All	30	120		٧
Emitter-Base B	Breakdown Voltage	$(I_C = 10 \mu A, I_F = 0)$	BV _{EBO}	All	5	10		٧
Collector-Emitter Dark Current (V _{CE} = 10V,		$(V_{CE} = 10V, I_F = 0, R_{BE} = 1M\Omega)$	I _{CER}	All		1	100	nA
Capacitance	Collector to Emitter	$(V_{CE} = 0, f = 1 \text{ MHz})$	C _{CE}	All		10		pF
	Collector to Base	(V _{CB} = 0, f = 1 MHz)	C _{CB}	All		80		pF
	Emitter to Base	(V _{EB} = 0, f = 1 MHz)	C _{EB}	All		15		pF

ISOLATION CHARACTERISTICS							
Characteristic	Test Conditions	Symbol	Device	Min	Typ**	Max	Units
Input-Output Isolation Voltage ⁽¹⁰⁾	(f = 60Hz, t = 1 min.)	V _{ISO}	All	5300			Vac(rms)
Isolation Resistance ⁽¹⁰⁾	V _{I-O} = 500 VDC, T _A = 25°C	R _{ISO}	All	10 ¹¹			Ω
Isolation Capacitance ⁽⁹⁾	V _{I-O} = 0, f = 1 MHz	C _{ISO}	All		0.7		pF
Common Mode Transient	$V_{CM} = 50 V_{P-P1}, R_L = 750\Omega, I_F = 0$	CM	MCT5210/11		5000		1///10
Rejection – Output High	$V_{CM} = 50 V_{P-P}, R_L = 1 K\Omega, I_F = 0$	CM _H	MCT5200/01		5000		V/µs
Common Mode Transient	$V_{CM} = 50 V_{P-P1}, R_L = 750\Omega, I_F = 1.6 mA$	CM	MCT5210/11		5000		\//uo
Rejection – Output Low	$V_{CM} = 50 V_{P-P1}, R_L = 1K\Omega, I_F = 5 mA$	- CM _L	MCT5200/01		3000		V/µs

^{**}All typical T_A=25°C



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Test Condition	ns	Symbol	Device	Min	Тур**	Max	Units
$I_F = 10 \text{ mA}, V_{CE} = 0.4 \text{ V}$			MCT5200	75			
$I_F = 5 \text{ mA}, V_{CE} = 0.4 \text{ V}$			MCT5201	120			
$I_F = 3.0 \text{ mA}, V_{CE} = 0.4 \text{ V}$		CTR _{CE(SAT)}	MCT5210	60			%
$I_F = 1.6 \text{ mA}, V_{CE} = 0.4 \text{ V}$, ,	MOTEO11	100			.
I _F = 1.0 mA, V _{CE} = 0.4 V			WIC 15211	75			
$I_F = 3.0 \text{ mA}, V_{CE} = 5.0 \text{ V}$			MCT5210	70			
$I_F = 1.6 \text{ mA}, V_{CE} = 5.0 \text{ V}$		CTR _(CE)	MCTEO11	150			%
$I_F = 1.0 \text{ mA}, V_{CE} = 5.0 \text{ V}$		l ` ´	WIC 15211	110			
$I_F = 10 \text{ mA}, V_{CB} = 4.3 \text{ V}$		MCT5200		0.2			
$I_F = 5 \text{ mA}, V_{CB} = 4.3 \text{ V}$			MCT5201	0.28			
		CTR _(CB)	MCT5210	0.2			%
			MOTEON	0.3			
			MC15211	0.25			
			MCT5200			0.4	
		V _{CE(SAT)}	MCT5201			0.4	V
			MCT5210			0.4	
I _F = 1.6 mA, I _{CE} = 1.6 mA		1 [MCT5211			0.4	
Test Condition	ns	Symbol	Device	Min	Тур	Max	Units
$R_L = 330 \Omega, R_{BE} = \infty$	$I_F = 3.0 \text{ mA}$		MOTEO40		10		μs
$R_L = 3.3 \text{ k}\Omega, R_{BE} = 39 \text{ k}\Omega$	$V_{CC} = 5.0 \text{ V}$		MC15210		7		
$R_L = 750 \Omega, R_{BE} = \infty$	I _F = 1.6mA				14		
$R_L = 4.7 \text{ k}\Omega, R_{BE} = 91 \text{ k}\Omega$	$V_{CC} = 5.0V$	_	MCT5211		15		
$R_L = 1.5 \text{ k}\Omega, R_{BE} = \infty$	$I_F = 1.0 \text{mA}$	¹ PHL			17		
R_L = 10 kΩ, R_{BE} = 160 kΩ	$V_{CC} = 5.0V$				24		
$V_{CE} = 0.4V, V_{CC} = 5V,$	$I_F = 10mA$		MCT5200		1.6	12	
$R_L = \text{fig. } 13, R_{BE} = 330 \text{ k}\Omega$	$I_F = 5mA$		MCT5201		3	30	
$R_L = 330 \Omega, R_{BE} = \infty$	$I_F = 3.0 \text{ mA}$		MOTEO10		0.4		
$R_L = 3.3 \text{ k}\Omega, R_{BE} = 39 \text{ k}\Omega$	$V_{CC} = 5.0 \text{ V}$		WIC 13210		8		
$R_L = 750 \Omega, R_{BE} = \infty$	I _F = 1.6mA				2.5		
$R_L = 4.7 \text{ k}\Omega, R_{BE} = 91 \text{ k}\Omega$	$V_{CC} = 5.0V$	_	MOTEO11		11		
$R_L = 1.5 \text{ k}\Omega, R_{BE} = \infty$	$I_F = 1.0 \text{mA}$	'PLH	MICT5211		7		μs
					16		1
$R_L = 10 \text{ k}\Omega, R_{BE} = 160 \text{ k}\Omega$	$V_{CC} = 5.0 V$						
	$V_{CC} = 5.0 \text{ V}$ $I_F = 10\text{mA}$		MCT5200		18	20	
$\begin{aligned} R_L &= 10 \text{ k}\Omega, \ R_{BE} = 160 \text{ k}\Omega \\ V_{CE} &= 0.4 \text{V}, V_{CC} = 5 \text{V}, \\ R_L &= \text{fig. 13}, \ R_{BE} = 330 \text{ k}\Omega \end{aligned}$			MCT5200 MCT5201			20	
$V_{CE} = 0.4V, V_{CC} = 5V,$	$I_F = 10mA$				18		
$V_{CE} = 0.4V, V_{CC} = 5V, \\ R_{L} = \text{fig. } 13, \ R_{BE} = 330 \ \text{k}\Omega$	I _F = 10mA I _F = 5mA	t _d	MCT5201		18 12	13	μs
$V_{CE} = 0.4V, V_{CC} = 5V,$ $R_{L} = \text{fig. } 13, R_{BE} = 330 \text{ k}\Omega$ $V_{CE} = 0.4V,$ $R_{BE} = 330 \text{ k}\Omega,$	$I_F = 10mA$ $I_F = 5mA$ $I_F = 10mA$	t _d	MCT5201 MCT5200		18 12 0.5	13 7	μs
	Test Condition I _F = 10 mA, V _{CE} = 0.4 V I _F = 5 mA, V _{CE} = 0.4 V I _F = 3.0 mA, V _{CE} = 0.4 V I _F = 1.6 mA, V _{CE} = 0.4 V I _F = 1.6 mA, V _{CE} = 0.4 V I _F = 1.0 mA, V _{CE} = 0.4 V I _F = 1.0 mA, V _{CE} = 5.0 V I _F = 1.6 mA, V _{CE} = 5.0 V I _F = 1.0 mA, V _{CE} = 5.0 V I _F = 1.0 mA, V _{CE} = 5.0 V I _F = 10 mA, V _{CE} = 4.3 V I _F = 5 mA, V _{CE} = 4.3 V I _F = 5 mA, V _{CE} = 4.3 V I _F = 1.0 mA, V _{CE} = 4.3 V I _F = 1.0 mA, I _{CE} = 7.5 mA I _F = 1.0 mA, I _{CE} = 7.5 mA I _F = 1.0 mA, I _{CE} = 1.6 mA I _F = 1.6 mA, I _{CE} = 1.6 mA I _F = 3.0 mA, I _{CE} = 1.6 mA I _F = 3.0 mA, I _{CE} = 1.6 mA I _F = 1.6 mA, I _{CE} = 1.6 mA I _F = 1.6 mA, I _{CE} = 1.6 mA I _F = 1.6 mA, I _{CE} = 1.6 mA I _F = 1.6 mA, I _{CE} = 1.6 mA I _F = 1.6 mA, I _{CE} = 1.6 mA I _F = 1.6 mA, I _{CE} = 1.6 mA I _F = 3.3 kΩ, I _{BE} = ∞ I _F = 4.7 kΩ, I _{BE} = 160 kΩ I _F = 1.5 kΩ, I _{BE} = ∞ I _F = 1.5 kΩ, I _{BE} = 330 kΩ I _F = 1.5 kΩ, I _{BE} = 330 kΩ I _F = 1.5 kΩ, I _{BE} = 330 kΩ I _F = 1.3 kΩ, I _{BE} = 39 kΩ I _F = 3.3 kΩ, I _{BE} = 39 kΩ I _F = 3.3 kΩ, I _{BE} = 39 kΩ I _F = 3.3 kΩ, I _{BE} = 39 kΩ I _F = 3.3 kΩ, I _{BE} = 39 kΩ I _F = 3.3 kΩ, I _{BE} = 39 kΩ I _F = 3.3 kΩ, I _{BE} = 39 kΩ I _F = 3.3 kΩ, I _{BE} = 39 kΩ I _F = 3.3 kΩ, I _{BE} = 39 kΩ I _F = 3.3 kΩ, I _{BE} = 39 kΩ I _F = 3.3 kΩ, I _{BE} = 39 kΩ I _F = 3.3 kΩ, I _{BE} = 39 kΩ I _F = 3.3 kΩ, I _{BE} = 39 kΩ I _F = 3.3 kΩ, I _{BE} = 39 kΩ I _F = 3.3 kΩ, I _{BE} = 39 kΩ I _F = 3.3 kΩ, I _{BE} = 39 kΩ I _F = 3.3 kΩ, I _F = 3.3 kΩ, I _F = 3.3 kΩ, I _F = 3.3 kΩ I _F = 3.3 kΩ, I _F = 3.3 kΩ I _F = 3.3 kΩ, I _F = 3.3 kΩ I _F = 3.3 kΩ, I _F = 3.3 kΩ I _F = 3.3 kΩ	$ \begin{array}{c ccccccccccccccccccccccccccccccccccc$	$\begin{split} I_F &= 10 \text{ mA}, \ V_{CE} = 0.4 \ V \\ I_F &= 5 \text{ mA}, \ V_{CE} = 0.4 \ V \\ I_F &= 3.0 \text{ mA}, \ V_{CE} = 0.4 \ V \\ I_F &= 1.6 \text{ mA}, \ V_{CE} = 0.4 \ V \\ I_F &= 1.0 \text{ mA}, \ V_{CE} = 0.4 \ V \\ I_F &= 1.0 \text{ mA}, \ V_{CE} = 0.4 \ V \\ I_F &= 1.0 \text{ mA}, \ V_{CE} = 5.0 \ V \\ I_F &= 1.6 \text{ mA}, \ V_{CE} = 5.0 \ V \\ I_F &= 1.0 \text{ mA}, \ V_{CE} = 5.0 \ V \\ I_F &= 10 \text{ mA}, \ V_{CE} = 4.3 \ V \\ I_F &= 5 \text{ mA}, \ V_{CB} = 4.3 \ V \\ I_F &= 3.0 \text{ mA}, \ V_{CE} = 4.3 \ V \\ I_F &= 1.0 \text{ mA}, \ V_{CE} = 4.3 \ V \\ I_F &= 1.0 \text{ mA}, \ V_{CE} = 4.3 \ V \\ I_F &= 1.0 \text{ mA}, \ I_{CE} = 1.8 \text{ mA} \\ I_F &= 1.0 \text{ mA}, \ I_{CE} = 1.8 \text{ mA} \\ I_F &= 3.0 \text{ mA}, \ I_{CE} = 1.8 \text{ mA} \\ I_F &= 3.0 \text{ mA}, \ I_{CE} = 1.8 \text{ mA} \\ I_F &= 3.0 \text{ mA}, \ I_{CE} = 1.8 \text{ mA} \\ I_F &= 3.0 \text{ mA}, \ I_{CE} = 1.8 \text{ mA} \\ I_F &= 1.6 \text{ mA}, \ I_{CE} = 1.8 \text{ mA} \\ I_F &= 1.6 \text{ mA}, \ I_{CE} = 1.8 \text{ mA} \\ I_F &= 1.6 \text{ mA}, \ I_{CE} = 1.8 \text{ mA} \\ I_F &= 1.0 \text{ mA}, \ I_{CE} = 1.8 \text{ mA} \\ I_F &= 1.0 \text{ mA}, \ I_{CE} = 1.8 \text{ mA} \\ I_F &= 1.0 \text{ mA}, \ I_{CE} = 1.8 \text{ mA} \\ I_F &= 1.0 \text{ mA}, \ I_{CE} = 1.8 \text{ mA} \\ I_F &= 1.0 \text{ mA}, \ I_{CE} = 1.0 \text{ mA} \\ V_{CC} &= 5.0 \ V \\ R_L &= 750 \ \Omega, \ R_{BE} = \infty \\ R_L &= 1.5 \text{ k}\Omega, \ R_{BE} = 30 \text{ k}\Omega \\ R_L &= 1.0 \text{ k}\Omega, \ R_{BE} = 30 \text{ k}\Omega \\ R_L &= 1.0 \text{ k}\Omega, \ R_{BE} = 30 \text{ k}\Omega \\ R_L &= 330 \ \Omega, \ R_{BE} = \infty \\ R_L &= 330 \ \Omega, \ R_{BE} = \infty \\ R_L &= 3.3 \text{ k}\Omega, \ R_{BE} = 30 \text{ k}\Omega \\ R_L &= 3.3 \text{ k}\Omega, \ R_{BE} = 30 \text{ k}\Omega \\ R_L &= 750 \ \Omega, \ R_{BE} = \infty \\ R_L &= 3.0 \ \Omega, \ R_{BE} = \infty \\ R_L &= 750 \ \Omega, \ R_{BE} = \infty \\ R_L &= 750 \ \Omega, \ R_{BE} = \infty \\ R_L &= 750 \ \Omega, \ R_{BE} = \infty \\ R_L &= 750 \ \Omega, \ R_{BE} = \infty \\ R_L &= 750 \ \Omega, \ R_{BE} = 91 \text{ k}\Omega \\ R_L &= 750 \ \Omega, \ R_{BE} = 91 \text{ k}\Omega \\ R_L &= 750 \ \Omega, \ R_{BE} = 91 \text{ k}\Omega \\ R_L &= 750 \ \Omega, \ R_{BE} = 91 \text{ k}\Omega \\ R_L &= 750 \ \Omega, \ R_{BE} = 91 \text{ k}\Omega \\ R_L &= 750 \ \Omega, \ R_{BE} = 91 \text{ k}\Omega \\ R_L &= 750 \ \Omega, \ R_{BE} = 91 \text{ k}\Omega \\ R_L &= 750 \ \Omega, \ R_{BE} = 91 \text{ k}\Omega \\ R_L &= 750 \ \Omega, \ R_{BE} = 91 \text{ k}\Omega \\ R_L &= 750 \ \Omega, \ R_{BE} =$	$ \begin{array}{c ccccccccccccccccccccccccccccccccccc$	$\begin{array}{c ccccccccccccccccccccccccccccccccccc$	$\begin{array}{c ccccccccccccccccccccccccccccccccccc$	$ \begin{array}{ c c c c c } \hline \textbf{Test Conditions} & \textbf{Symbol} & \textbf{Device} & \textbf{Min} & \textbf{Typ^{**}} & \textbf{Max} \\ \hline l_F = 10 \text{ mA}, V_{CE} = 0.4 \text{ V} \\ l_F = 5 \text{ mA}, V_{CE} = 0.4 \text{ V} \\ l_F = 3.0 \text{ mA}, V_{CE} = 0.4 \text{ V} \\ l_F = 1.6 \text{ mA}, V_{CE} = 0.4 \text{ V} \\ l_F = 1.0 \text{ mA}, V_{CE} = 0.4 \text{ V} \\ l_F = 3.0 \text{ mA}, V_{CE} = 0.4 \text{ V} \\ l_F = 1.0 \text{ mA}, V_{CE} = 5.0 \text{ V} \\ l_F = 1.0 \text{ mA}, V_{CE} = 5.0 \text{ V} \\ l_F = 1.0 \text{ mA}, V_{CE} = 5.0 \text{ V} \\ l_F = 1.0 \text{ mA}, V_{CE} = 5.0 \text{ V} \\ l_F = 1.0 \text{ mA}, V_{CE} = 4.3 \text{ V} \\ l_F = 5 \text{ mA}, V_{CB} = 4.3 \text{ V} \\ l_F = 5 \text{ mA}, V_{CE} = 4.3 \text{ V} \\ l_F = 5 \text{ mA}, V_{CE} = 4.3 \text{ V} \\ l_F = 5 \text{ mA}, V_{CE} = 4.3 \text{ V} \\ l_F = 1.0 \text{ mA}, V_{CE} = 4.3 \text{ V} \\ l_F = 5 \text{ mA}, I_{CE} = 6 \text{ mA} \\ l_F = 5 \text{ mA}, I_{CE} = 1.8 \text{ mA} \\ l_F = 5 \text{ mA}, I_{CE} = 1.6 \text{ mA} \\ l_F = 1.6 \text{ mA}, I_{CE} = 1.8 \text{ mA} \\ l_F = 1.6 \text{ mA}, I_{CE} = 1.8 \text{ mA} \\ l_F = 1.6 \text{ mA}, I_{CE} = 1.6 \text{ mA} \\ \hline \textbf{MCT5201} & 0.4 \\ \hline \textbf{MCT5201} & 0.4 \\ \hline \textbf{MCT5201} & 0.2 \\ \hline \textbf{MCT5201} & 0.4 \\ \hline \textbf{MCT5201} & 0.2 \\ \hline \textbf{MCT5201} & 0.4 \\ \hline \textbf{MCT5211} & 0.4 \\ \hline \textbf{MCT5210} & 0.4 \\ \hline \textbf{MCT5211} & 0.4 \\ \hline \textbf{MCT5210} & 0.4 \\ \hline \textbf{MCT5210} & 0.4 \\ \hline \textbf{MCT5211} & 0.4 \\ \hline \textbf{MCT5211} & 0.4 \\ \hline \textbf{MCT5210} & 0.4 \\ \hline \textbf{MCT5211} & 0.4 \\ \hline \textbf{MCT5210} & 0.4 \\ \hline \textbf{MCT5210} & 0.4 \\ \hline \textbf{MCT5210} & 0.4 \\ \hline \textbf{MCT5211} & 0.4 \\ \hline \textbf{MCT5210} & 0.4 \\ \hline MCT521$



MCT5200 MCT5201 MCT5210 MCT5211

TRANSFER CHARACTERISTICS (T _A = 0°C to 70°C Unless otherwise specified.) (Continued)								
DC Characteristics	Test Conditio	ns	Symbol	Device	Min	Typ**	Max	Units
(7)	$V_{CE} = 0.4V,$	I _F = 10mA		MCT5200		15	18	
Storage Time ⁽⁷⁾ $R_{BE} = 330 \text{ k}\Omega,$ $R_{L} = 1 \text{ k}\Omega, V_{CC} = 5V$	I _F = 5mA	t _s	MCT5201		10	13	μs	
(0)	$V_{CE} = 0.4V,$	I _F = 10mA		MCT5200		16	30	
Fall Time ⁽⁸⁾	$R_{BE} = 330 \text{ k}\Omega,$ $R_{L} = 1 \text{ k}\Omega, V_{CC} = 5V$	I _F = 5mA	t _f	MCT5201		16	30	μs

^{**}All typicals at T_A = 25°C

Notes

- 1. DC Current Transfer Ratio (CTR_{CE}) is defined as the transistor collector current (I_{CE}) divided by the input LED current (I_{F}) x 100%, at a specified voltage between the collector and emitter (V_{CE}).
- 2. The collector base Current Transfer Ratio (CTR_{CB}) is defined as the transistor collector base photocurrent(I_{CB}) divided by the input LED current (I_F) time 100%.
- Referring to Figure 14 the T_{PHL} propagation delay is measured from the 50% point of the rising edge of the data input pulse to the 1.3V point on the falling edge of the output pulse.
- Referring to Figure 14 the T_{PLH} propagation delay is measured from the 50% point of the falling edge of data input pulse to the 1.3V point on the rising edge of the output pulse.
- 5. Delay time (t_d) is measured from 50% of rising edge of LED current to 90% of Vo falling edge.
- 6. Rise time (t_r) is measured from 90% to 10% of Vo falling edge.
- 7. Storage time (t_s) is measured from 50% of falling edge of LED current to 10% of Vo rising edge.
- 8. Fall time (t_f) is measured from 10% to 90% of Vo rising edge.
- 9. C_{ISO} is the capacitance between the input (pins 1, 2, 3 connected) and the output, (pin 4, 5, 6 connected).
- 10. Device considered a two terminal device: Pins 1, 2, and 3 shorted together, and pins 5, 6 and 7 are shorted together.



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TYPICAL PERFORMANCE GRAPHS

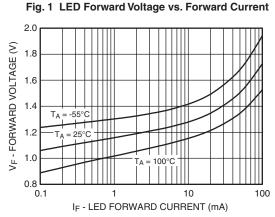


Fig. 2 Normalized Current Transfer Ratio vs. **Forward Current** 1.2 1.0 NORMALIZED CTRCE 0.8 0.6 0.4 $I_F = 5mA$ 0.2 $V_{CE} = 5V$ $T_A = 25^{\circ}C$ 0 0.1 100 IF - FORWARD CURRENT (mA)

Fig. 3 Normalized CTR vs. Temperature

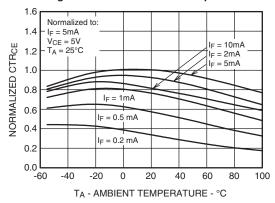


Fig. 4 Normalized Collector vs.
Collector - Emitter Voltage

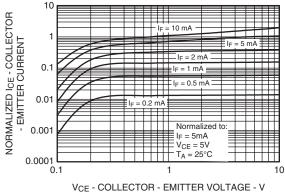


Fig. 5 Normalized Collector Base Photocurrent Ratio vs. Forward Current

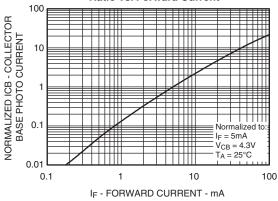
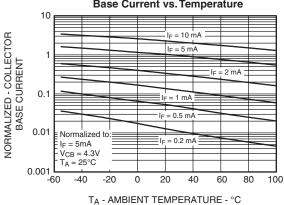


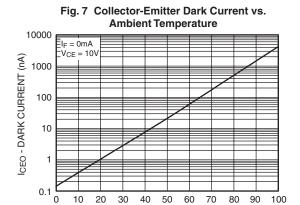
Fig. 6 Normalized Collector - Base Current vs. Temperature





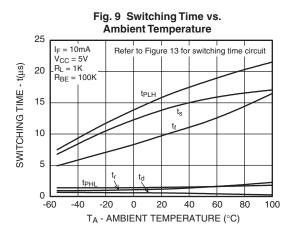
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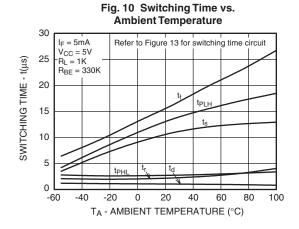
TYPICAL PERFORMANCE GRAPHS (Continued)

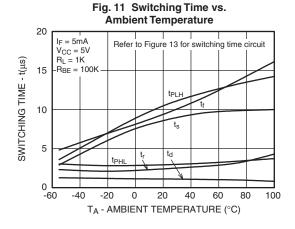


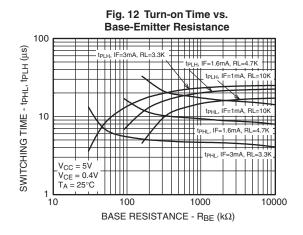
TA - AMBIENT TEMPERATURE (°C)

Fig. 8 Switching Time vs. **Ambient Temperature** 30 I_F = 10mA Refer to Figure 13 for switching time circuit V_{CC} = 5V R_L = 1K 25 SWITCHING TIME - t(µs) R_{BE} = 330K 20 tplh 15 10 5 0 -60 -20 0 20 40 100 TA - AMBIENT TEMPERATURE (°C)











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TYPICAL ELECTRO-OPTICAL CHARACTERISTICS (TA = 25°C Unless Otherwise Specified)

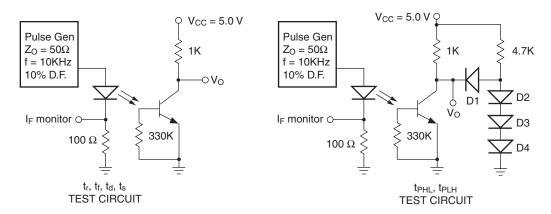


Figure 13.

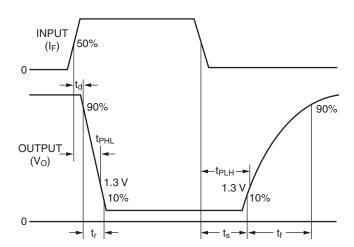
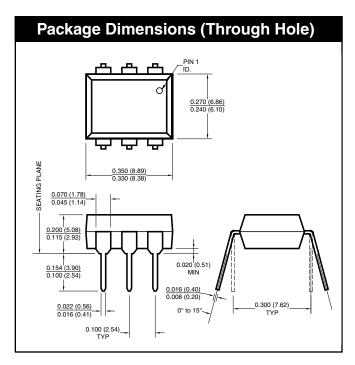
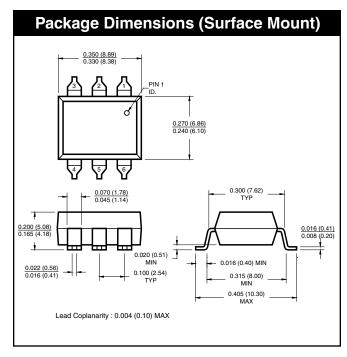


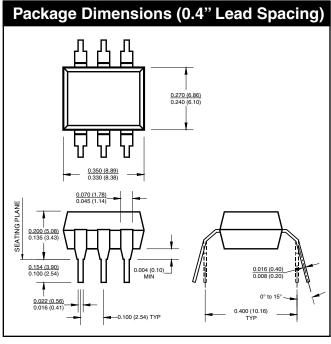
Figure 14. Switching Circuit Waveforms

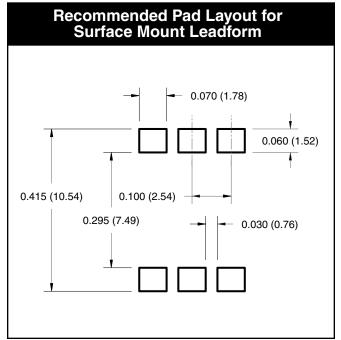


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Note

All dimensions are in inches (millimeters)

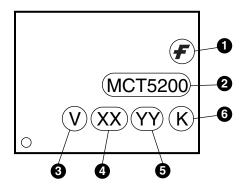


MCT5200	MCT5201	MCT5210	MCT5211
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ORDERING INFORMATION

Option	Order Entry Identifier	Description
S	.S	Surface Mount Lead Bend
SD	.SD	Surface Mount; Tape and Reel
W	.W	0.4" Lead Spacing
300	.300	VDE 0884
300W	.300W	VDE 0884, 0.4" Lead Spacing
3S	.3\$	VDE 0884, Surface Mount
3SD	.3SD	VDE 0884, Surface Mount, Tape and Reel

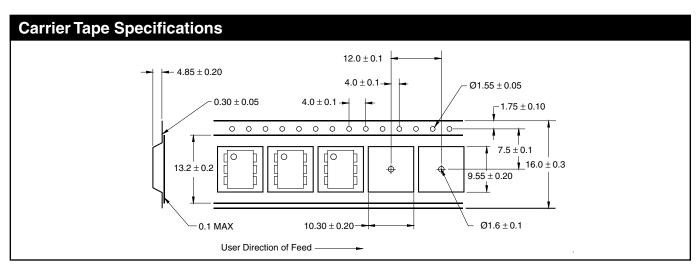
MARKING INFORMATION



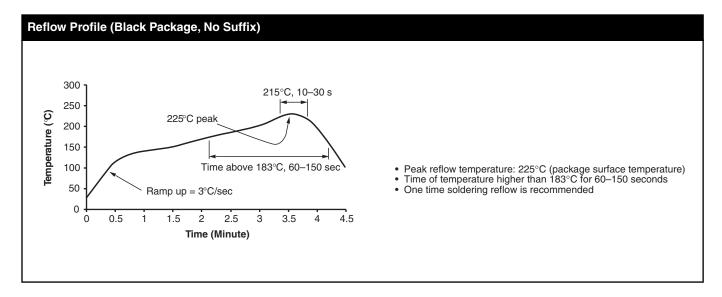
Definiti	Definitions					
1	Fairchild logo					
2	Device number					
3	VDE mark (Note: Only appears on parts ordered with VDE option – See order entry table)					
4	Two digit year code, e.g., '03'					
5	Two digit work week ranging from '01' to '53'					
6	Assembly package code					



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NOTEAll dimensions are in inches (millimeters)





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MCT5210

6-Pin DIP Low Current Input Phototransistor Output Optocoupler

Contents

- General description
- Features
- Applications
- Product status/pricing/packaging
 Qualification Support
- Order Samples
- Safety agency certificates

General description

The MCT52XX series consists of a high-efficiency AlGaAs, infrared emitting diode, coupled with an NPN phototransistor in a six pin dual-in-line package.

The MCT52XX is well suited for CMOS to LSTT/TTL interfaces, offering 250% CTR CE(SAT) with 1 mA of LED input current. When an LED input current of 1.6 mA is supplied data rates to 20K bits/s are possible. The MCT52XX can easily interface LSTTL to LSTTL/TTL, and with use of an external base to emitter resistor data rates of 100K bits/s can be achieved.

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Features

- High CTR_{CE(SAT)} comparable to Darlingtons
- CTR guaranteed 0°C to 70°C
- High common mode transient rejection 5kV/µs
- Data rates up to 150 kbits/s (NRZ)
- Underwriters Laboratory (UL) recognized (file #E90700)
- VDE recognized (file #94766)
 - Add option 300 (e.g., MCT5211.300)

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Applications

BUY

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Related Links

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How to order products

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Support

Sales support

Quality and reliability

Design center

- CMOS to CMOS/LSTTL logic isolationLSTTL to CMOS/LSTTL logic isolation
- RS-232 line receiver

- Telephone ring detector
 AC line voltage sensing
 Switching power supply

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Product status/pricing/packaging

BUY

Product	Product status	Pb-free Status	Package type	Leads	Packing method
MCT5210	Lifetime Buy		DIP-B	6	BULK
MCT5210300	Lifetime Buy	Ø	DIP-B	6	BULK
MCT5210300W	Lifetime Buy	Ø	DIP-B	6	BULK
MCT52103S	Lifetime Buy	Ø	SMDIP-B	6	BULK
MCT52103SD	Lifetime Buy	Ø	SMDIP-B	6	TAPE REEL
MCT5210S	Lifetime Buy	Ø	SMDIP-B	6	BULK
MCT5210SD	Lifetime Buy	Ø	SMDIP-B	6	TAPE REEL
MCT5210W	Lifetime Buy	Ø	DIP-B	6	BULK



Indicates product with Pb-free second-level interconnect. For more information click here.

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Safety agency certificates

Certificate		Agency
E90700, Vol. 1 (936 K)	UL (1577)	Underwriters Laboratories Inc.
E90700, Vol. 1 (936 K)	C-UL	Underwriters Laboratories Inc.
<u>0122085</u> (677 K)	SEMKO	SEMKO
P01101067 (1638 K)	NEMKO	NEMKO
FI 16812 (964 K)	FIMKO	FIMKO

310684-02 (623 K)	DEMKO	DEMKO Testing & Certification
<u>1027742</u> (2305 K)	CSA	Canadian Standards Association
<u>94766</u> (1673 K)	VDE	VDE Pruf-und Zertifizierungsinstitut

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Qualification Support

Click on a product for detailed qualification data

Product
MCT5210
MCT5210300
MCT5210300W
MCT52103S
MCT52103SD
MCT5210S
MCT5210SD
MCT5210W

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